L Number	Hits	Search Text	DB	Time stamp
-	7788	deep adj well	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/26 19:16
-	11266	dark near2 current	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/26 19:17
-	4	((complementar$4 near2 (mosfet or misfet or (metal adj (oxide or insulat$4) adj semiconducor adj (fet or field))) or cmos or cmisfet) near4 (image near2 sens$4)) and (deep adj well) and (dark near2 current)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/26 19:19
-	4	(((complementar$4 near2 (mosfet or misfet or (metal adj (oxide or insulat$4) adj semiconducor adj (fet or field))) or cmos or cmisfet) near4 (image near2 sens$4)) and (deep adj well) and (dark near2 current)) and (@ad < "20030710")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/27 12:53
-	1	6084259.pn. and (revers$4 near2 bias$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/26 19:34
-	4	(((complementar$4 near2 (mosfet or misfet or (metal adj (oxide or insulat$4) adj semiconducor adj (fet or field))) or cmos or cmisfet) near4 (image near2 sens$4)) and (deep adj well) and (dark near2 current)) and (@ad < "20030710")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/27 12:54
-	2	6084259.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/30 12:32
-	1	6084259.pn. and nois$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/30 12:44
-	0	6084259.pn. and latch	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/30 12:44
-	53	(((image near2 sens$4) or (ccd or charg$4 near coupl$4 near device)) same (revers$4 near2 bias$4)) and ((image near2 sens$4) near4 (ccd or charg$4 near coupl$4 near device)) and (complementar$4 near2 (mosfet or misfet or (metal adj (oxide or insulat$4) adj semiconducor adj (fet or field))) or cmos or cmisfet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 16:34
-	1637	((438/73) or (438/75) or (438/76) or (438/200)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/28 17:24